

Data sheet acquired from Harris Semiconductor SCHS018C – Revised September 2003

# CMOS Dual Complementary Pair Plus Inverter

High-Voltage Types (20-Volt Rating)

■ CD4007UB types are comprised of three n-channel and three p-channel enhancement-type MOS transistors. The transistor elements are accessible through the package terminals to provide a convenient means for constructing the various typical circuits as shown in Fig. 2.

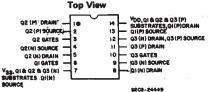
More complex functions are possible using multiple packages. Numbers shown in parentheses indicate terminals that are connected together to form the various configurations listed.

The CD4007UB types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Applications:

- Extremely high-input impedance amplifiers
- Shapers
- Inverters
- Threshold detector
- Linear amplifiers
- **■** Crystal oscillators

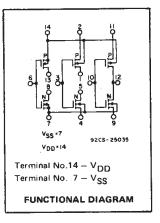
# TERMINAL DIAGRAM



# **CD4007UB Types**

#### Features:

- Standardized symmetrical output characteristics
- Medium Speed Operation tpHL, tpLH = 30 ns (typ.) at 10 V
- 100% tested for quiescent current at 20 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"
- Maximum input current of 1 μA at 18 V over full package-temperature range;
   100 nA at 18 V and 25°C



#### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	Lif	UNITS	
	MIN.	MAX.	
Supply-Voltage Range			
(For T <sub>A</sub> = Full Package Temperature Range)	3	18	v

#### STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	OITION	IS	LIMIT	rs at i	NDICAT	ED TE	MPERA	UNITS		
ISTIC	Vo	VIN	VDD					+25			Civit
	(v)	(V)	(V)	-55	<b>-40</b>	+85	+125	Min.	Тур.	Max.	
Quiescent Dévice	_	0,5	5	0.25	0.25	7.5	7.5	_	0.01	0.25	
Current,		0,10	10	0.5	0.5	15	15		0.01	0,5	μA
IDD Max.	- <u>-                                   </u>	0,15	15	1	1	30	30		0.01	1	μ-
	-	0,20	20	5	5	150	150		0.02	5	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source)	2.5	0,5	5	-2	1.8	-1.3	-1.15	-1.6	-3.2		
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6		
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	2.4	-3.4	-6.8	_	
Output Voltage:	_	0,5	5		0	.05		-	0	0.05	
Low-Level,	_	.0;10	10		0	.05		_	0	0.05	
VOL Max.	_	0,15	15		0	.05		-	0	0.05	l v
Output Voltage:	_	0,5	5		4	.95		4.95	5	-	] `
High-Level,	_	0,10	10		9	.95		9.95	10	_	
VOH Min.	_	0,15	15		14	1.95		14.95	15	<u> </u>	
Input Low	4.5	-	5			1		_	_	1	
Voltage,	9	-	10			2		_		2	
VIL Max.	13.5	-	15			2.5		-		2.5	v
Input High	0.5	<u> </u>	5			4		4	_	_	*
Voltage,	1	-	10			8		8			
VIH Min.	1.5	T -	15		1	2.5		12.5		_	
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 <sup>-5</sup>	±0.1	μА

#### CD4007UB Types

MAXIMUM RATINGS, Absolute-Maximum Values:DC SUPPLY-VOLTAGE RANGE,  $(V_{DD})$ -0.5V to +20VVoltages referenced to  $V_{SS}$  Terminal)-0.5V to  $V_{DD}$  +0.5VINPUT VOLTAGE RANGE, ALL INPUTS-0.5V to  $V_{DD}$  +0.5VDC INPUT CURRENT, ANY ONE INPUT $\pm 10mA$ POWER DISSIPATION PER PACKAGE (PD):500mWFor  $T_A = -55^{\circ}C$  to  $+100^{\circ}C$ 500mWFOR  $T_A = +100^{\circ}C$  to  $+125^{\circ}C$ Derate Linearity at  $12mW/^{\circ}C$  to 200mWDEVICE DISSIPATION PER OUTPUT TRANSISTOR100mWFOR  $T_A = FULL$  PACKAGE-TEMPERATURE RANGE (All Package Types)100mWOPERATING-TEMPERATURE RANGE ( $T_{atg}$ ) $-55^{\circ}C$  to  $+125^{\circ}C$ STORAGE TEMPERATURE RANGE ( $T_{atg}$ ) $-65^{\circ}C$  to  $+150^{\circ}C$ LEAD TEMPERATURE (DURING SOLDERING): $+265^{\circ}C$ At distance  $1/16 \pm 1/32$  inch  $(1.59 \pm 0.79mm)$  from case for 10s max $+265^{\circ}C$ 

a) Triple Inverters	6 8 3 5 5
(14,2,11); (8,13); (1,5); (7,4,9)	92CS-15350

(13,2); (1,11); (12,5,8); (7,4,9)

# DYNAMIC ELECTRICAL CHARACTERISTICS at T\_A = 25°C; Input t\_r, t\_f = 20 ns, C\_L = 50 pF, R\_L = 200 K $\Omega$

	COND	ITIONS	LIA			
CHARACTER		V <sub>DD</sub> Volts	Тур.	Max.	UNITS	
Propagation Delay T		5	55	110		
	tPHL.		10	30	60	ns
	<b>tPLH</b>		15	25	50	1
		1	5	100	200	
Transition Time	tTHL, tTLH		10	50	100	ns
			15	40	80	1
Input Capacitance	CIN	Any Input		10	15	pF

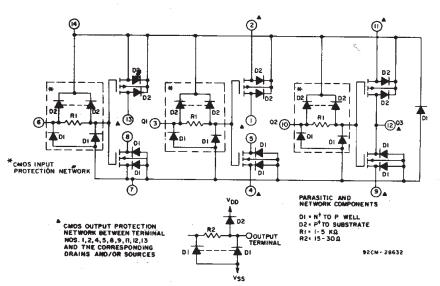


Fig. 1 — Detailed schematic diagram of CD4007UB showing input, output, and parasitic diodes.

c) 3-Input NAND Gate 30 00 12 (1,12,13); (2,14,11); 9205-15348 (4,8); (5,9)

#### d) Tree (Relay) Logic

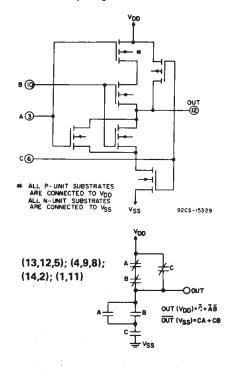
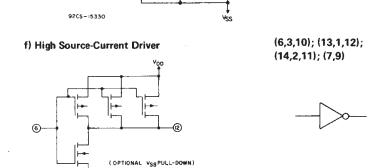


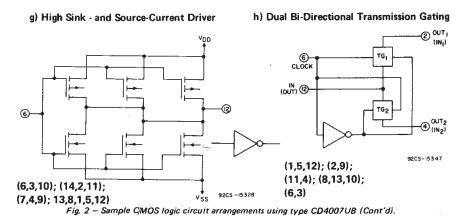
Fig. 2 — Sample C'MOS logic circuit arrangements using type CD4007UB.

# CD4007UB Types

# e) High Sink-Current Driver (6,3,10); (8.5, 12); (11,14); 7,4,9)



92CS-15327



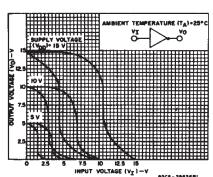


Fig. 6 – Minimum and maximum voltage-transfer characteristics for inverter.

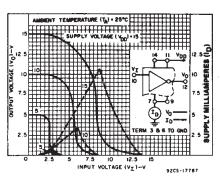


Fig. 7 – Typical current and voltage-transfer characteristics for inverter.

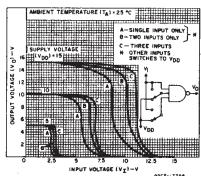


Fig. 3 – Typical voltage-transfer characteristics for NAND gate.

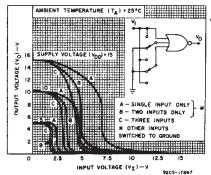


Fig. 4 — Typical voltage-transfer characteristics for NOR gate.

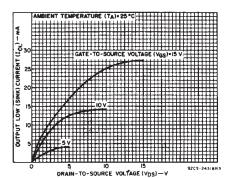


Fig. 5 — Typical output low (sink) current characteristics.

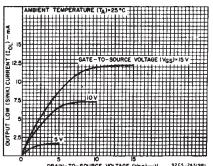


Fig. 8 – Minimum output low (sink)

current characteristics.

# CD4007UB Types

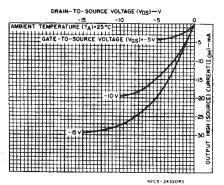


Fig. 9 ~ Typical output high (source) current characteristics.

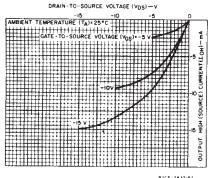


Fig. 10 – Minimum output high (source) current characteristics.

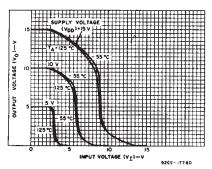


Fig. 11 — Typical voltage-transfer characteristics as a function of temperature.

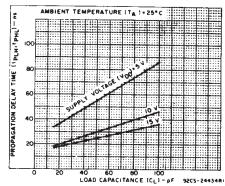


Fig. 12 — Typical propagation delay time vs. load capacitance.

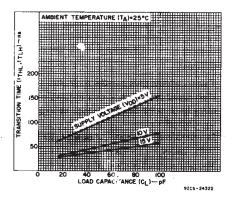


Fig. 13 — Typical transition time vs. load capacitance.

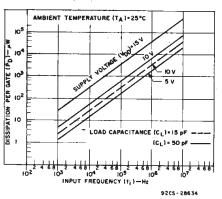


Fig. 14 — Typical dissipation vs. frequency characteristics.

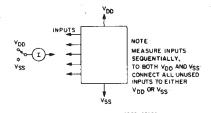


Fig. 15 - Input current test circuit.

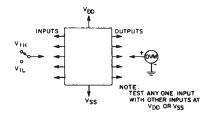


Fig. 16 - Input voltage test circuit.

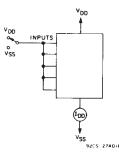
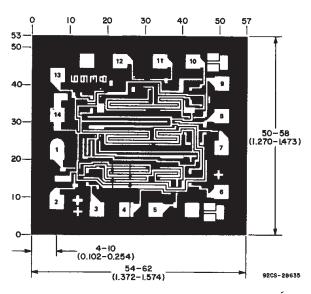


Fig. 17 - Quiescent device current test circuit.



**DIMENSIONS AND PAD LAYOUT FOR CD4007UBH** 

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as Indicated, Grid graduations are in mile (10<sup>-3</sup> inch).

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4007UBE	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4007UBE	Samples
CD4007UBEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4007UBE	Samples
CD4007UBF	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4007UBF	Samples
CD4007UBF3A	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4007UBF3A	Samples
CD4007UBM	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4007UBM	Samples
CD4007UBM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4007UBM	Samples
CD4007UBMT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4007UBM	Samples
CD4007UBNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4007UB	Samples
CD4007UBNSRG4	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4007UB	Samples
CD4007UBPW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM007UB	Samples
CD4007UBPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM007UB	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

# PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD4007UB, CD4007UB-MIL:

Catalog : CD4007UB

Military: CD4007UB-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

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# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All ullilerisions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4007UBM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4007UBMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4007UBNSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4007UBPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4007UBM96	SOIC	D	14	2500	853.0	449.0	35.0
CD4007UBMT	SOIC	D	14	250	210.0	185.0	35.0
CD4007UBNSR	SO	NS	14	2000	853.0	449.0	35.0
CD4007UBPWR	TSSOP	PW	14	2000	853.0	449.0	35.0

# PACKAGE MATERIALS INFORMATION

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4007UBE	N	PDIP	14	25	506	13.97	11230	4.32
CD4007UBE	N	PDIP	14	25	506	13.97	11230	4.32
CD4007UBEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4007UBEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4007UBM	D	SOIC	14	50	506.6	8	3940	4.32
CD4007UBPW	PW	TSSOP	14	90	530	10.2	3600	3.5

# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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